

Supplementary Materials

Enhancement of the VIS-NIR absorption in a sulfurated-high-entropy film

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Table S1. The average reflectance, transmittance, and absorptance of (NiCrCuFeSi)O, (NiCrCuFeSi)OS, and CuS films at the wavelength range of 300~1700 nm.

	average reflectance	average transmittance	average absorptance
(NiCrCuFeSi)O	0.16	0.54	0.30
(NiCrCuFeSi)OS	0.08	0.02	0.90
CuS	0.35	0.02	0.63

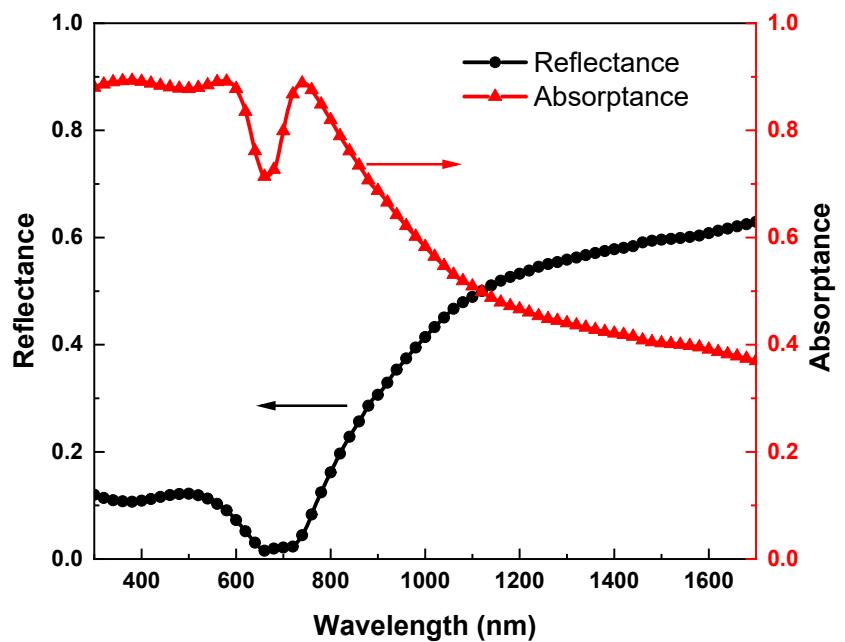


Figure S1. The reflectance and absorptance at the range of 300~1700 nm of CuS film with a thickness of 400 nm. The refractive index n and extinction coefficient k are from reference (Diliérgos-Godines, et al. 2019).

Reference:

C. J. Diliérgos-Godines, D. I. Lombardero-Juarez, R. Machorro-Mejía, R. S. González and M. Pal, *Opt. Mater.*, 2019, **91**, 147–154.